BU2520AF

GENERAL DESCRIPTION

New generation, high-voltage, high-speed switching npn transistor in a plastic full-pack envelope intended for use in horizontal deflection circuits of large screen colour television receivers up to 32 kHz.

QUICK REFERENCE DATA

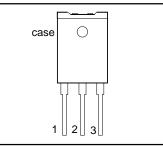
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	800	V
Ic	Collector current (DC)		-	10	Α
	Collector current peak value		-	25	A
P _{tot}	Total power dissipation	T _{bs} ≤ 25 °C	-	45	W
P _{tot} V _{CEsat}	Collector-emitter saturation voltage	T _{hs} ≤ 25 °C I _C = 6.0 A; I _B = 1.2 A	-	5.0	V
I _{Csat}	Collector saturation current		6.0	-	Α
t _f	Fall time	$I_{Csat} = 6.0 \text{ A}; I_{B(end)} = 0.85 \text{ A}$	0.2	0.35	μs

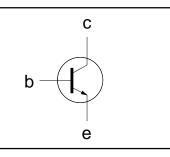
PINNING - SOT199

PIN CONFIGURATION

SYMBOL

PIN	DESCRIPTION
1	base
2	collector
3	emitter
case	isolated





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	800	V
I _c	Collector current (DC)		-	10	Α
I _{CM}	Collector current peak value		-	25	Α
I _B	Base current (DC)		-	6	Α
I _{BM}	Base current peak value		-	9	Α
-I _{B(AV)}	Reverse base current	average over any 20 ms period	-	150	mA
-I _{BM}	Reverse base current peak value ¹		-	6	Α
P _{tot}	Total power dissipation	$T_{hs} \leq 25 \degree C$	-	45	W
T _{stg}	Storage temperature		-65	150	°C
T _j	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Junction to heatsink	without heatsink compound	-	3.7	K/W
R _{th j-hs}	Junction to heatsink	with heatsink compound	-	2.8	K/W
R _{th j-a}	Junction to ambient	in free air	35	-	K/W

¹ Turn-off current.

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Repetitive peak voltage from all three terminals to external heatsink	$R.H. \leq 65~\%$; clean and dustfree	-		2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	22	-	рF

STATIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

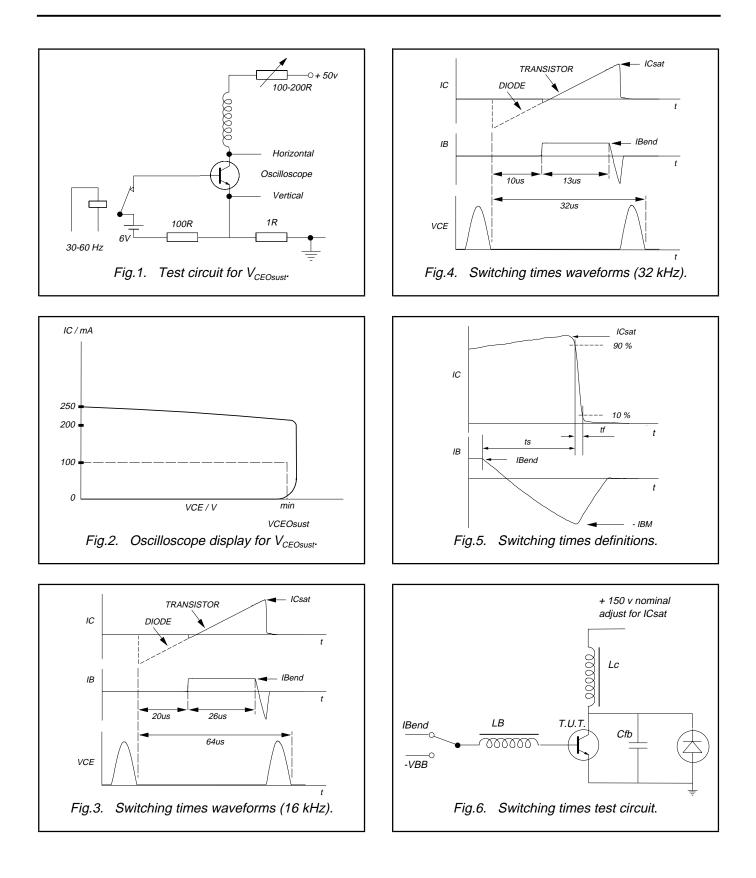
PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Collector cut-off current ²	$V_{BE} = 0 V; V_{CE} = V_{CESMmax}$	-	-	1.0	mA mA
Emitter out off ourrent	$ T_i = 125 \degree C$				mA
Emitter-base breakdown voltage	$I_{\rm B} = 1 \mathrm{mA}$	7.5	13.5	-	V
	L = 25 mH	800	-	-	V
	$I_{\rm C} = 6.0 \text{ A}; I_{\rm B} = 1.2 \text{ A}$ $I_{\rm C} = 6.0 \text{ A}; I_{\rm B} = 1.2 \text{ A}$	-	-	5.0 1.1	V V
DC current gain	$I_{c} = 100 \text{ mA}; V_{ce} = 5 \text{ V}$	- 5	13 7	- 9.5	
	Collector cut-off current ² Emitter cut-off current Emitter-base breakdown voltage Collector-emitter sustaining voltage Collector-emitter saturation voltage Base-emitter saturation voltage	Collector cut-off current 2 $V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$ Emitter cut-off current $V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$ Emitter cut-off current $V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$ Emitter-base breakdown voltage $V_{BE} = 7.5 \text{ V}; $	Collector cut-off current 2 $V_{BE} = 0 \text{ V}; $	Collector cut-off current 2 $V_{BE} = 0 V; V_{CE} = V_{CESMmax};$ -Emitter cut-off current $V_{BE} = 0 V; V_{CE} = V_{CESMmax};$ -Emitter cut-off current $V_{BE} = 0 V; V_{CE} = V_{CESMmax};$ -Emitter-base breakdown voltage $V_{BB} = 7.5 V; I_C = 0 A$ -Collector-emitter sustaining voltage $V_{BB} = 1 mA$ 7.5Collector-emitter saturation voltage $I_B = 0 A; I_C = 100 mA;$ 800Collector-emitter saturation voltage $I_C = 6.0 A; I_B = 1.2 A$ -DC current gain $I_C = 100 mA; V_{CE} = 5 V$ -	Collector cut-off current 2 $V_{BE} = 0 \text{ V}; $

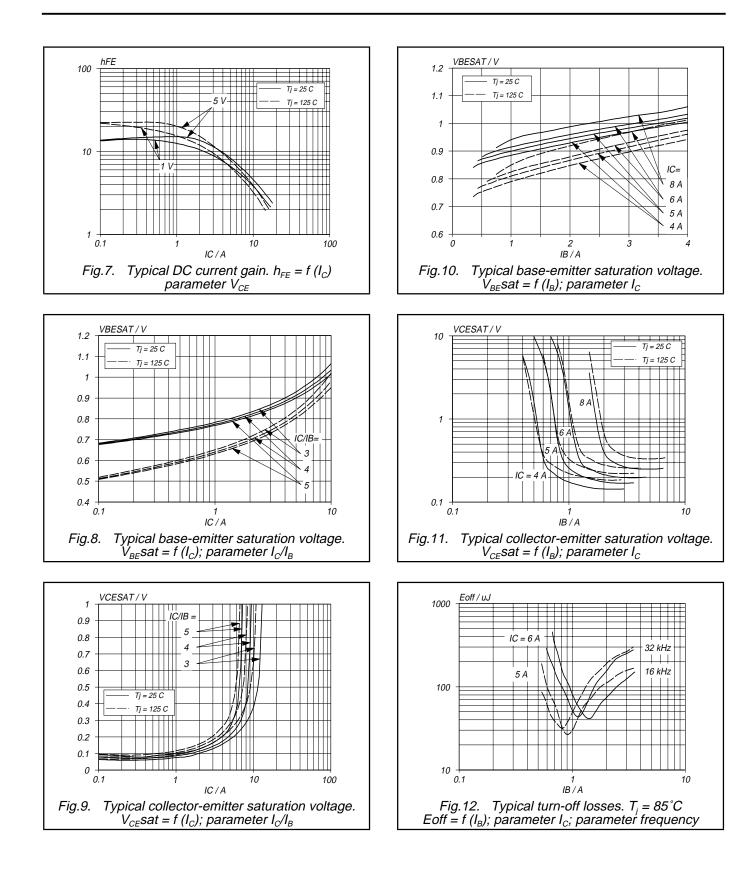
DYNAMIC CHARACTERISTICS

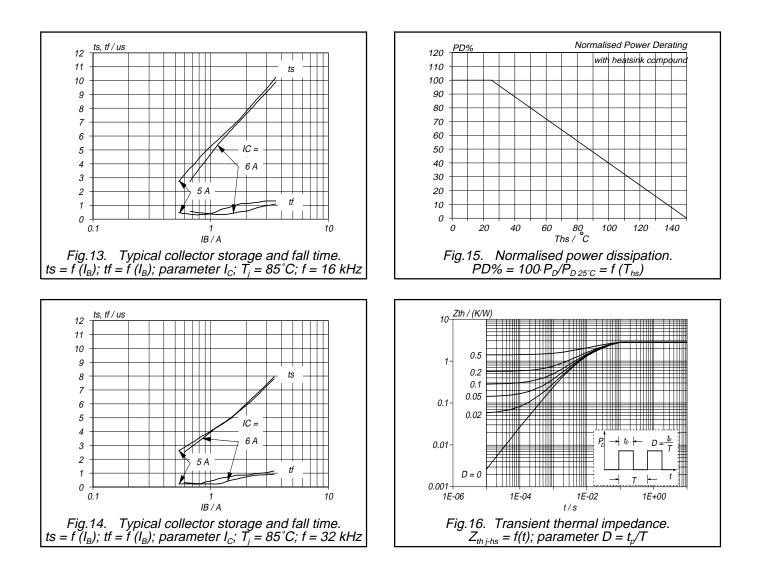
 $T_{hs} = 25$ °C unless otherwise specified

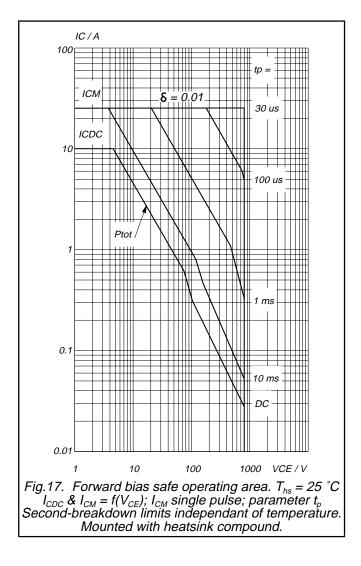
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
C _c	Collector capacitance	I _E = 0 A; V _{CB} = 10 V; f = 1 MHz	115	-	pF
t _s t _f	Switching times (32 kHz line deflection circuit) Turn-off storage time Turn-off fall time	$ \begin{array}{l} I_{Csat} = 6.0 \text{ A}; \ L_{C} = 330 \ \mu\text{H}; \ C_{fb} = 9 \ n\text{F}; \\ I_{B(end)} = 0.85 \ \text{A}; \ L_{B} = 3.45 \ \mu\text{H}; \\ \text{-}V_{BB} = 4 \ \text{V}; \ (\text{-}dI_{B}/dt = 1.2 \ \text{A} \ / \ \mu\text{s}) \end{array} $	3.0 0.2	4.0 0.35	μs μs
	Switching times (16 kHz line deflection circuit)	$\begin{array}{l} I_{\text{Csat}} = 6.0 \text{ A}; L_{\text{C}} = 650 \mu\text{H}; C_{\text{fb}} = 19 n\text{F}; \\ I_{\text{B}(\text{end})} = 1.0 A; L_{\text{B}} = 5.3 \mu\text{H}; \text{-V}_{\text{BB}} = 4 \text{V}; \\ (\text{-d}I_{\text{B}}/\text{dt} = 0.8 \text{A} / \mu\text{s}) \end{array}$			
t _s t _f	Turn-off storage time Turn-off fall time		4.5 0.35	5.5 0.5	μs μs

² Measured with half sine-wave voltage (curve tracer).





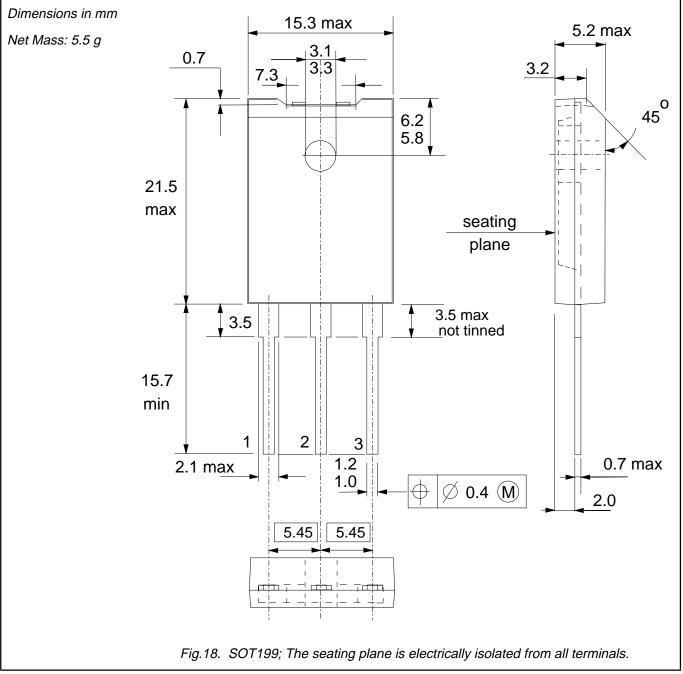




BU2520AF

Product specification

MECHANICAL DATA



Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	pjective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	reliminary specification This data sheet contains preliminary data; supplementary data may be published late			
Product specification	This data sheet contains final product specifications.			
Limiting values				
or more of the limiting val operation of the device at	Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
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